

Description

The **WD-GFA261-H10F** is a small package, high SNR and multimode top port digital MEMS microphone with 1-bit PDM output, consists of a MEMS sensor, a low noise level amplifier, and a Σ - Δ modulator.

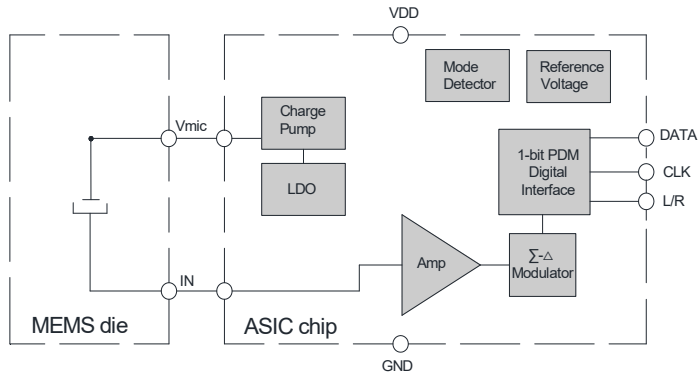
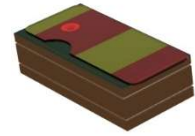
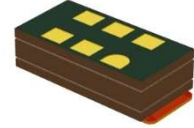


Fig. 1 Microphone block diagram



Top View



Bottom View

Key Features

- ✧ 4.0x2.0x1.1 mm Top Port
- ✧ 1-bit PDM Output
- ✧ Narrow Sensitivity +/-1dBFS
- ✧ High SNR of 64dBA
- ✧ Flat Frequency Performance
- ✧ Multi Mode(Sleep,Low power,Normal)
- ✧ Compatible with Standard SMD Reflow Technology
- ✧ RoHSCompliance&Halogen Free

Typical Applications

- ✧ Mobilephones
- ✧ NotebookComputers
- ✧ Smart Speakers
- ✧ Wearable Electronics
- ✧ Digital Video Cameras
- ✧ Smart Home Electronics

Maximum Ratings

Stresses at the maximum ratings shown in Table 1 may cause permanent damage to the device. These are stress ratings only at which the device may not function when an operation at these or any other condition beyond those specified under “Electro-Acoustic Specifications”.

Table 1 Maximum Ratings

Parameters	Maximum Ratings	Unit
Power supply voltage	6.5	V
Operation temperature range	-40~85	°C
Storage temperature range	-40~125	°C

Electro-Acoustic Specifications

Table 2 Normal Mode Electrical Specifications

Test condition: +25±2℃, 60%~70% RH, 86~106Kpa, F_{CLK}=2.4MHz, V_{DD}=1.8V, no load, unless otherwise noted.

Symbol	Description	Min.	Typ.	Max.	Units
F _{CLK}	Clock Frequency	1.3	2.4	4.8	MHz
I _{DD}	Supply Current ¹		770	900	uA
S	Sensitivity ³ , 94dB SPL@1KHz	-27	-26	-25	dBFS ²
ΔS	Sensitivity drop	-0.25		0.25	dBFS
SNR	20-20KHz Bandwidth, A-weighted	62	64		dB(A)
THD	94dB SPL@1KHz		0.25	0.5	%
AOP	10%THD@1KHz	118	121		dB SPL
PSR+N	Measured with 217Hz, 100mVpp square wave			-75	dBFS
PSRR	Measured with 1KHz, 200mVpp sine wave	50			dBFS
Phase	100-10KHz	±5			degree

Table 3 Low Power Mode Electrical Specifications

Test condition: +25±2℃, 60%~70% RH, 86~106Kpa, F_{CLK}=768KHz, V_{DD}=1.8V, no load, unless otherwise noted.

Symbol	Description	Min.	Typ.	Max.	Units
F _{CLK}	Clock Frequency	150	768	900	KHz
I _{DD}	Supply Current		330	500	uA
S	Sensitivity, 94dB SPL@1KHz	-27	-26	-25	dBFS
ΔS	Sensitivity drop	-0.25		0.25	dBFS
SNR	20Hz~8KHz Bandwidth, A-weighted		64		dB(A)
THD	94dB SPL@1KHz		0.25	0.5	%
AOP	10%THD@1KHz	118	121		dB SPL
PSR+N	Measured with 217Hz, 100mV _{pp} square wave			-75	dBFS
PSRR	Measured with 1KHz, 200mVpp sine wave	50			dBFS
Phase	100-6KHz	±5			degree

Note 1: The current consumption depends on the applied clock frequency and the load on the DATA output

Note 2: dBFS=20*logA/B, where A is the level of signal, and B is the level that corresponds to full-scale level

Note 3: Relative to the rms level of a sine wave with positive amplitude equal to 100% 1s density and negative amplitude equal to 0% 1s density

Note 4: Frequency response, sensitivity and current consumption are tested by 100% on product line.

Table 4 General Electrical Specifications

Test condition: +25±2℃, 60%~70% RH, 86~106Kpa, no load, unless otherwise noted.

Symbol	Description	Min.	Typ.	Max.	Units
V _{DD}	Supply Voltage	1.62	1.8	3.6	V
I _{SLEEP}	Power Consumption of Stand By		3	50	uA
F _{CLK}	Clock Frequency	Standby Mode	0	10	KHz
		Low Power Mode	150	768	KHz
		Normal Mode	1.3	2.4	MHz
Data Format		1/2 Cycle PDM			
Directivity		Omni-directional			
Polarity	Increasing sound pressure	Increasing density of 1's			
I _{SC}	Short circuit current Grounded DATA	1		20	mA
C _{LOAD}	Load capacitance			100	pF
Reset time	Time to start up in any mode after V _{DD} has been off for more than 10ms, while CLOCK remained on			20	ms
Start-up time	Start-up into normal mode or LP mode			20	ms
Mode-switch time	Mode-switch Normal mode to LP mode or LP mode to Normal mode			20	ms

Table 5 Digital input—output specifications

Parameter	Symbol	Min.	Typ.	Max.	Unit	Note
Clock duty cycle		40	50	60	%	
Operation Voltage	V _{DD}	1.62		3.6	V	
Input Logic Low Level	V _{IL}	-0.3		0.35×V _{DD}	V	
Input Logic High Level	V _{IH}	0.65×V _{DD}		V _{DD} +0.3	V	
Output Logic Low Level	V _{OL}			0.45	V	
Output Logic High Level	V _{OH}	V _{DD} -0.45			V	
Clock rise time	t _{CR}			6	ns	35%~65%
Clock fall time	t _{CF}			6	ns	65%~35%
Delay time for data valid	t _{DV}	40		100	ns	Delay time from clock edge(0.50 x V _{DD}) to data valid(<V _{OL} or > V _{OH})

Delay time for data driven	t_{DD}	25		50	ns	Delay time from clock edge (50% VDD) to data driven.
Delay time for data high Z	t_{HZ}	5		20	ns	Delay time from clock edge(50% VDD) to data high impedance state

Table 6 L/R Channel Configuration

Channel	L/R pad connection	DATA driven	Data high Z
DATA1	GND	CLK falling edge	CLK rising edge
DATA2	VDD	CLK rising edge	CLK falling edge

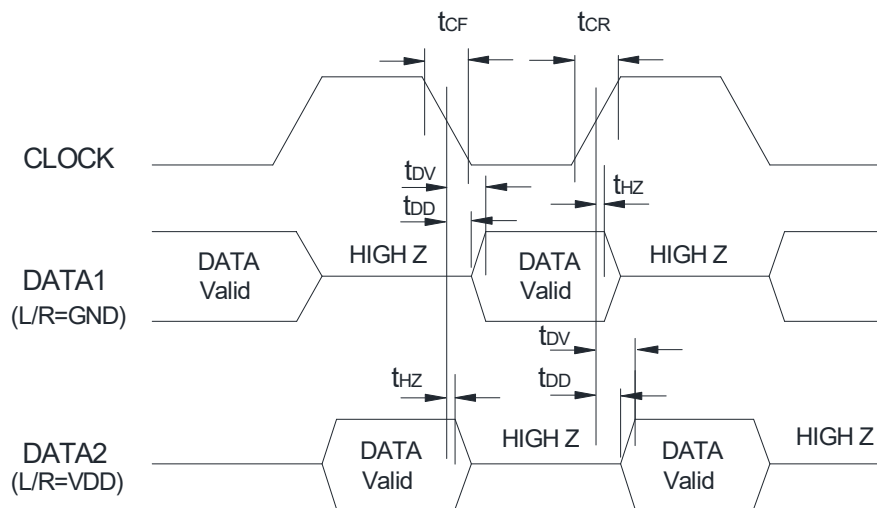


Fig. 2 Recommended timing diagram

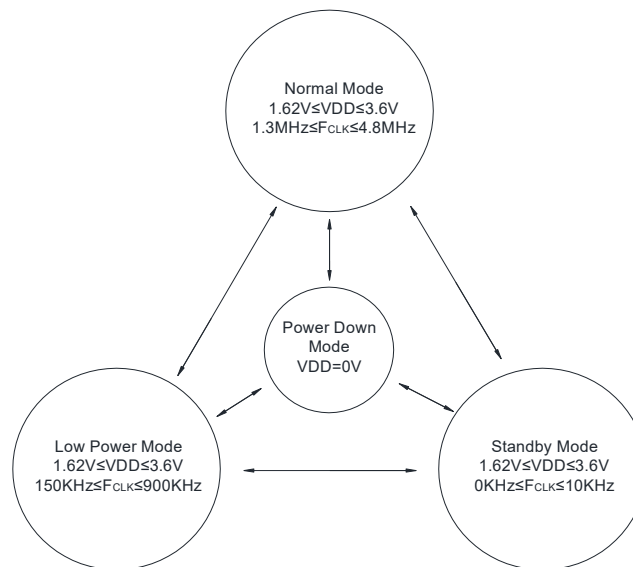


Fig. 3 State diagram

Performance Curves

All curves are tested under 1.8V, 2.4MHz unless otherwise noted.

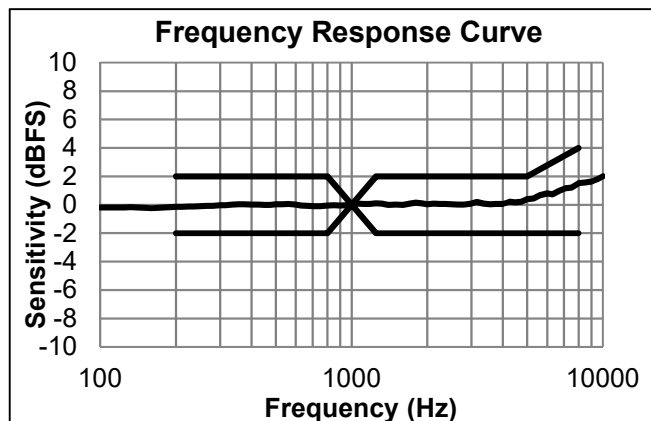


Fig. 4 Normal mode FR normalized to 1KHz

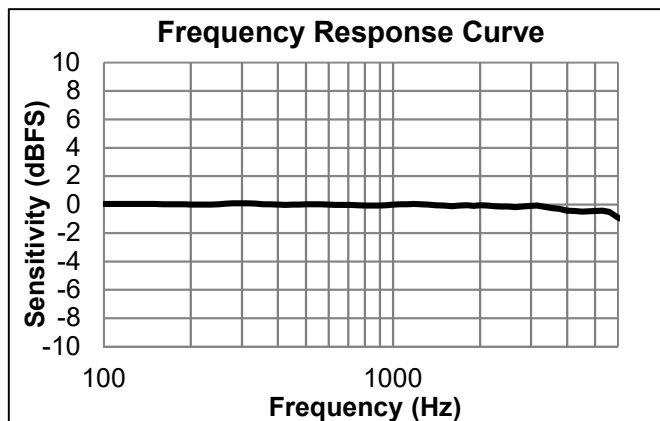


Fig. 5 Low power mode FR normalized to 1KHz

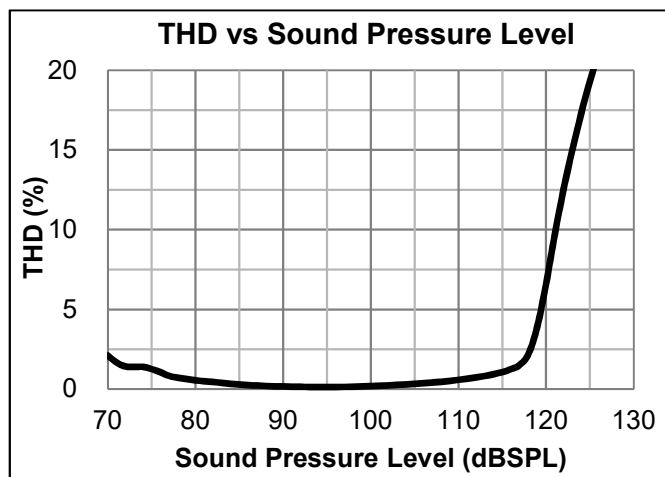


Fig. 6 Typical THD vs Sound Pressure Level

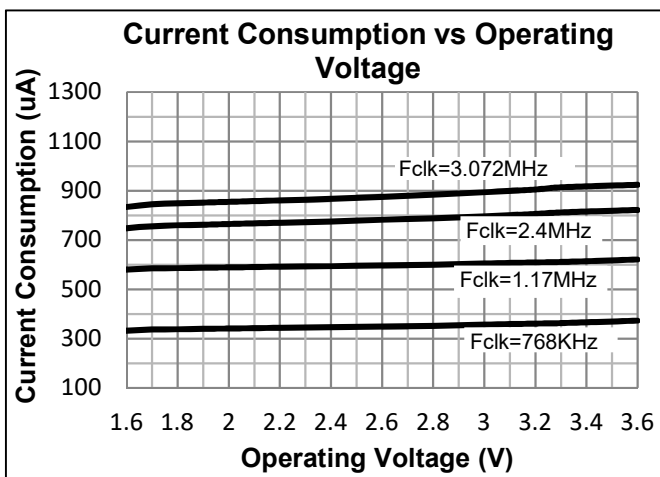


Fig. 7 Typical Current Consumption curve

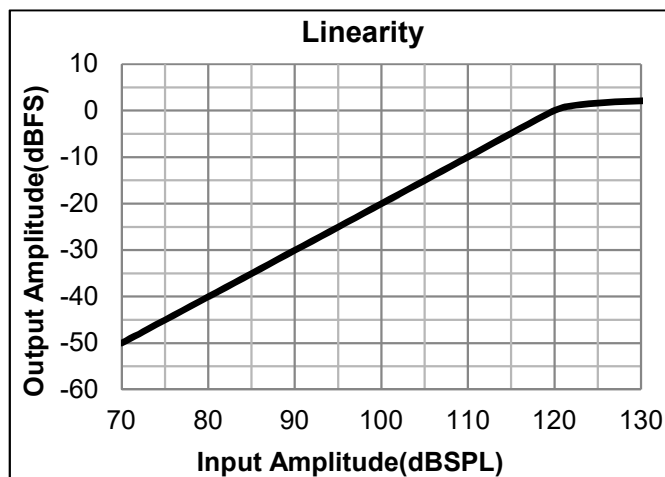


Fig. 8 Linearity

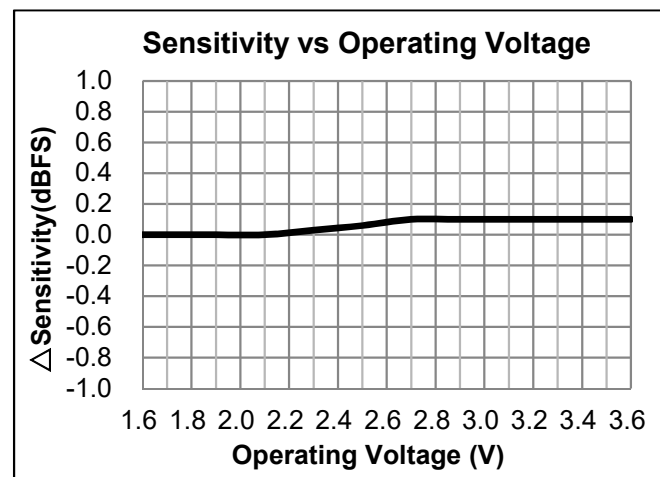


Fig. 9 Sensitivity vs Operating Voltage

Measurement System Setup

Test signal: Sinusoid, Sweep,

Step: 1/12 octave

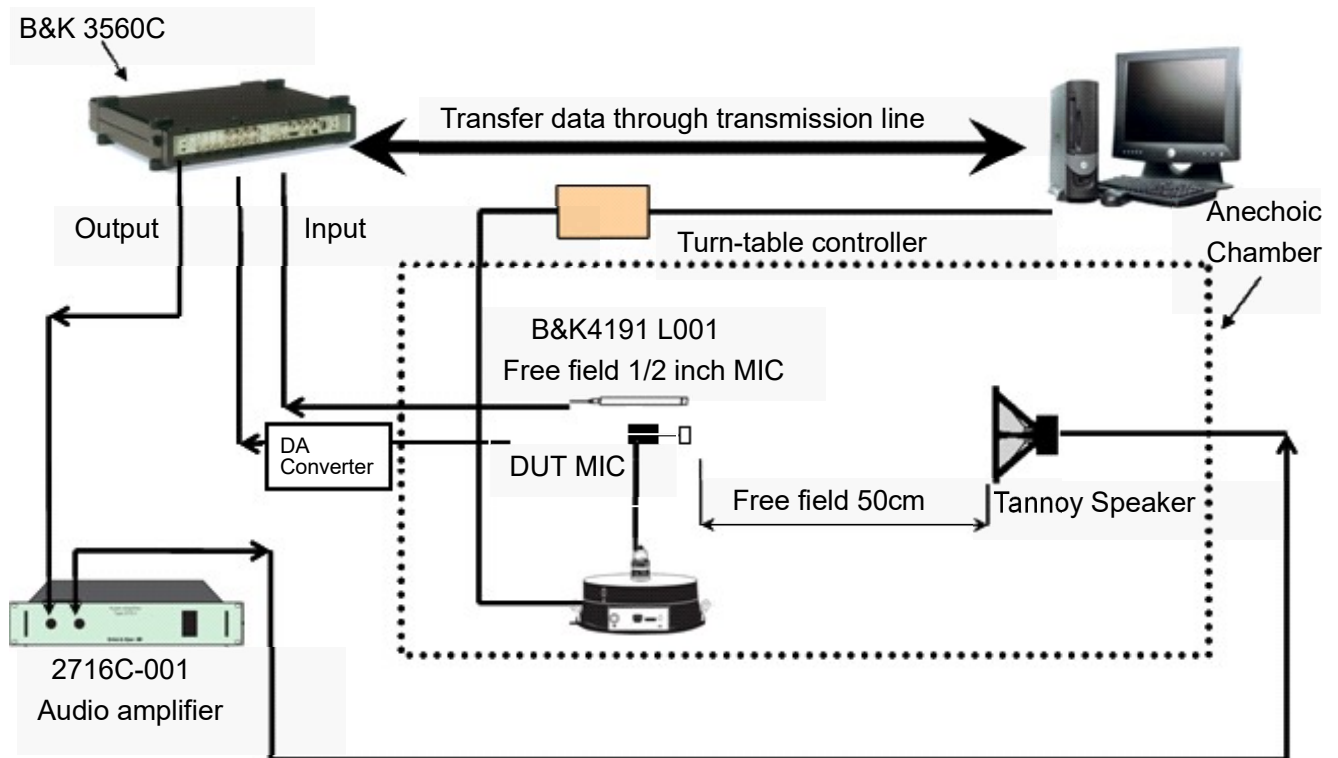


Fig. 10 Measurement System Setup

Typical Application Circuit

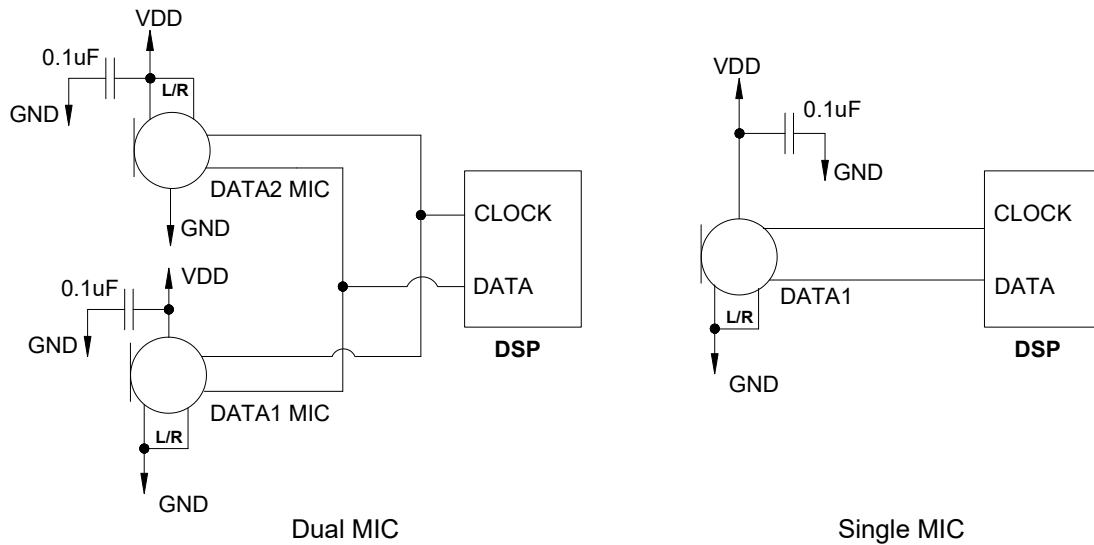


Fig. 11 Typical Application Circuit

Note1:L/R must be connected to VDD or GND even single MIC use.

Note2:A 0.1uF ceramic type decoupling capacitor strongly recommended for every microphone and it should be placed as close to the VDD pad to reduce the noise on power supply;

The trace connected to each pad of capacitor should be as short as possible, and should stay on one layer of PCB without via. For the best performance, recommend to place the capacitor equidistance from power and ground pins of microphone, or slightly closer to the power pin if space not allowed. System ground should connect to far side of the capacitor, as shown in fig.12.

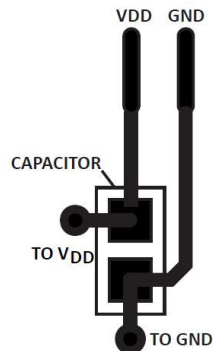
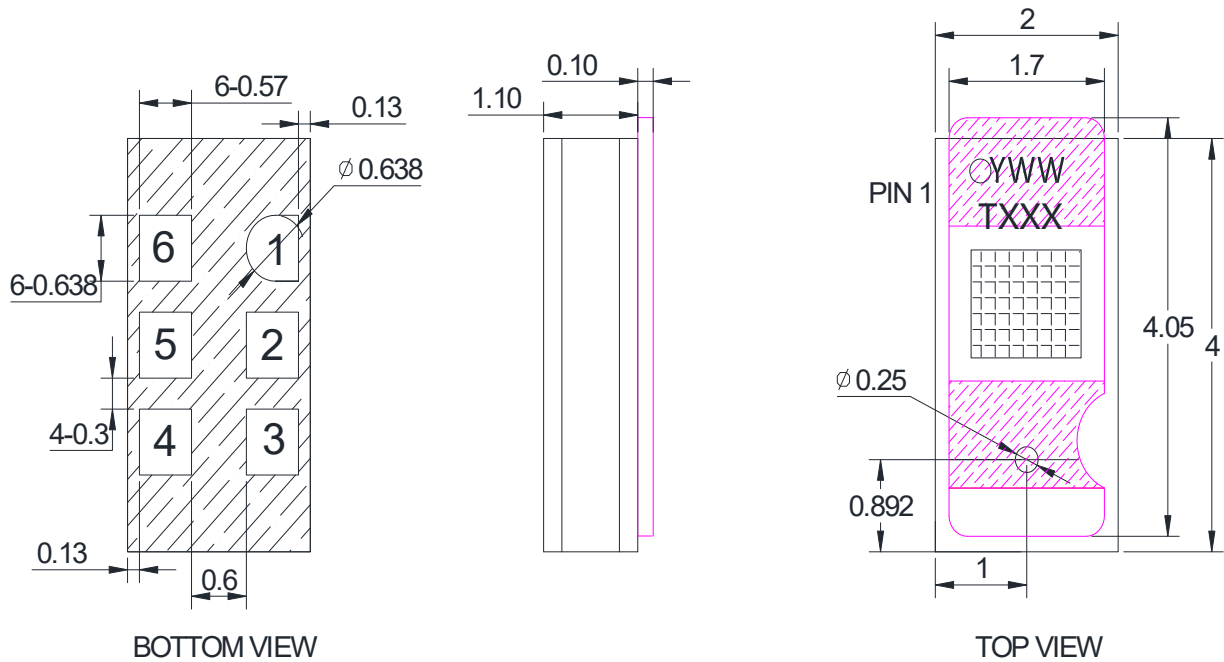


Fig. 12 Recommended Power Supply Decoupling Capacitor Layout

Note3: Do not use a pull-up or pull-down resistor on the PDM data signal line, because it can pull the signal to an incorrect state during the period that the signal line is restarted.

Note3: When long wire is used to connect the CLK of codec and microphone, a 50~100Ω resistor should be placed near the codec to reduce signal over-shoot or ringing.

Mechanical Specifications



Unit: mm Unmarked Tolerance: ± 0.1

Fig. 9 Dimension

Item	Dimension	Tolerance
Length	4.0	± 0.1
Width	2.0	± 0.1
Height	1.1	± 0.1
Acoustic Port	0.25	± 0.05

PIN	Definition	Description
1	VDD	Power Supply
2	GND	Ground
3	DATA	PDM output
4	CLK	Clock input
5	GND	Ground
6	L/R	L/R select (No internal pull-down. Must be connected to VDD or GND)

Note:

- All Ground Pin must be connected to the ground in end application
- The L/R pin is suggested to connect to GND during single mic application.
- Identification Marking

○: Polarity sign Y: Year WW: Week

T: GETTOP XXX: Serial Number



2D Barcode

Reliability Specifications

After conducting any of the following tests, the sensitivity change of DUT shall be less than $\pm 3\text{dBFS}$ from its initial value unless otherwise noted, and shall keep its initial operation and appearance.

Table 7 Electrical Specifications

No.	Item	Test condition
1	Preconditioning	24 hour bake at 125°C, followed by 168 hours at 85°C, 85%RH, followed by 3 passes solder reflow only for the following three tests: High Humidity & High Heat operating Test High Humidity & High Heat operating Test Thermal Shocking Test
2	Hi-Temperature Storage Test	105 \pm 3°C, 1000h, recover for two hours
3	Hi-Temperature operating Test	105 \pm 3°C, under upper limit bias, 1000h, recover for two hours
4	Low-Temperature storage Test	-40 \pm 3°C, 1000h, recover for two hours
5	Low-Temperature operating Test	-40 \pm 3°C, under upper limit bias, 1000h, recover for two hours
6	High Humidity & High Heat operating Test	85 \pm 3°C, 85%RH, under upper limit bias, 1000h, recover for two hours, there should be no corrosion and deformation inside of microphone after testing
7	High Humidity & High Heat operating Test	65 \pm 3°C, 95%RH, under upper limit bias, 168h, recover for two hours, there should be no corrosion and deformation inside of microphone after testing
8	Thermal Shocking Test	Double-Case Method, -40°C for 15mins \rightarrow 125°C for 15 mins, 100 cycles, recover for two hours
9	Vibration Test	Each 12mins for X, Y and Z axes, Frequency: 20~2000Hz, Peak Acceleration 20g, recover for two hours
10	Drop Test	Height: 1.5m Fixture Weight: 150g (Sound Hole Diameter in the fixture is $\geq 0.8\text{mm}$) Reference Surface: slippery marble floor Duration: 4 corners*4 times, 6 faces*4 times The sensitivity change should be less than 1dB after testing
11	Tumbling Test	Height: 1.0m Fixture Weight: 150g (Sound Hole Diameter in the fixture is $\geq 0.8\text{mm}$) Duration: 300 times Recommended Time: 10-11 times/Min The sensitivity change should be less than 1dB after testing

12	ESD Test 1	<p>a. HMB Discharge Position: I/O pins Charge Voltage: $\pm 3000V$ Discharge Network: 100pF & 1500Ω</p> <p>b. CDM Discharge Position: I/O pins Charge Voltage: $\pm 250V$</p>
13	ESD Test 2	<p>The tests are performed acc. to IEC61000-4-2 level 3:</p> <p>a. Contact Discharge Discharge Position: Output of Microphone Charge Voltage: $\pm 6000VDC$ Discharge Network: 150pF & 330Ω</p> <p>b. Air Discharge Discharge Position: Sound Hole Charge Voltage: $\pm 8000VDC$ Discharge Network: 150pF & 330Ω</p>
14	Structure Shock Test	10000g, Duration: 0.1ms, each 3 shocks for X/Y/Z 3 axes, The sensitivity change should be less than 1dB after testing
15	Reflow	3 reflow cycles with peak temperature of +260 $^{\circ}C$ according to reflow profile

Packaging Details

- * Use ESD reel and tape for microphone packaging.
- * Anti-static measures should be applied during packaging operation.

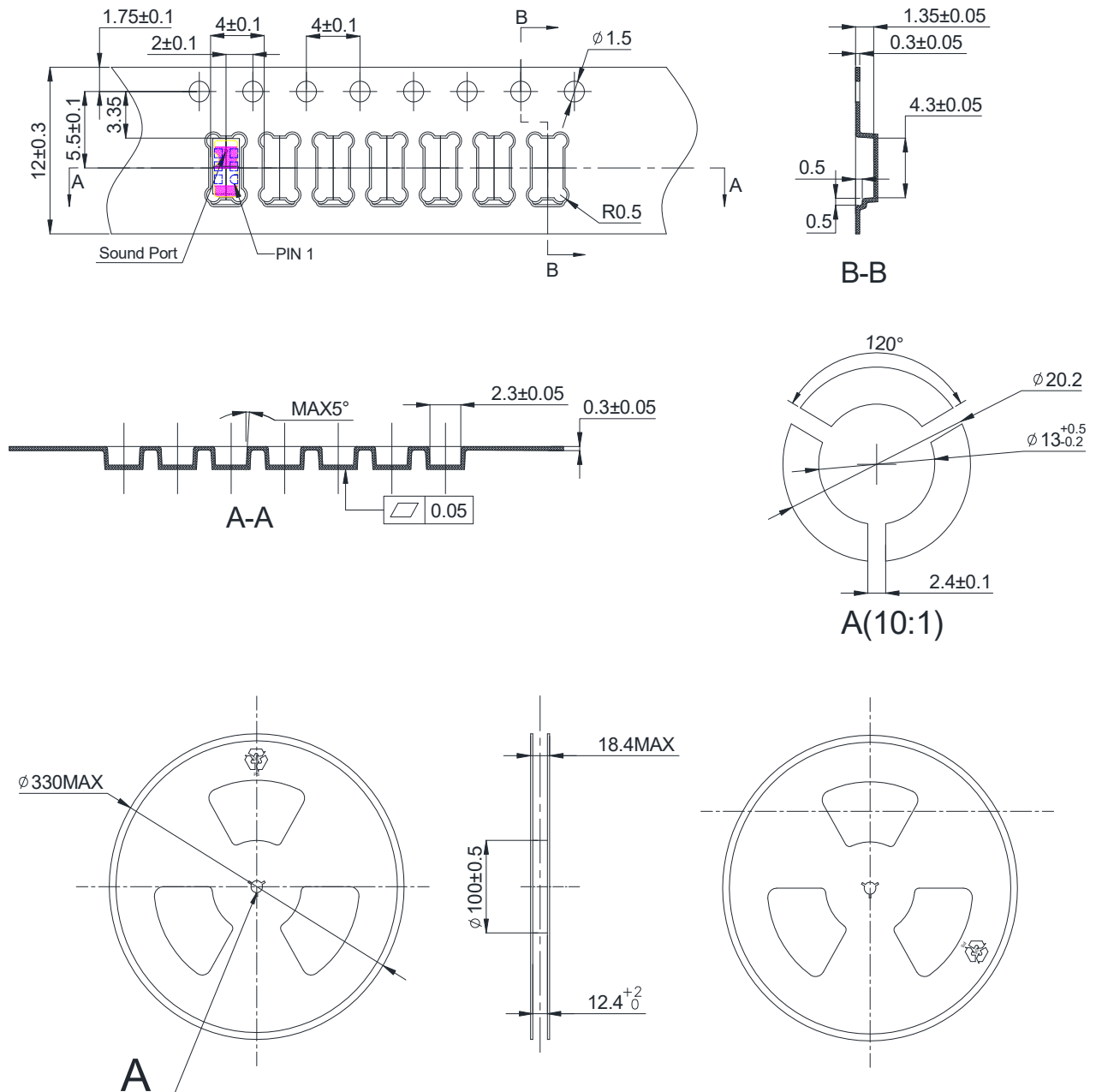
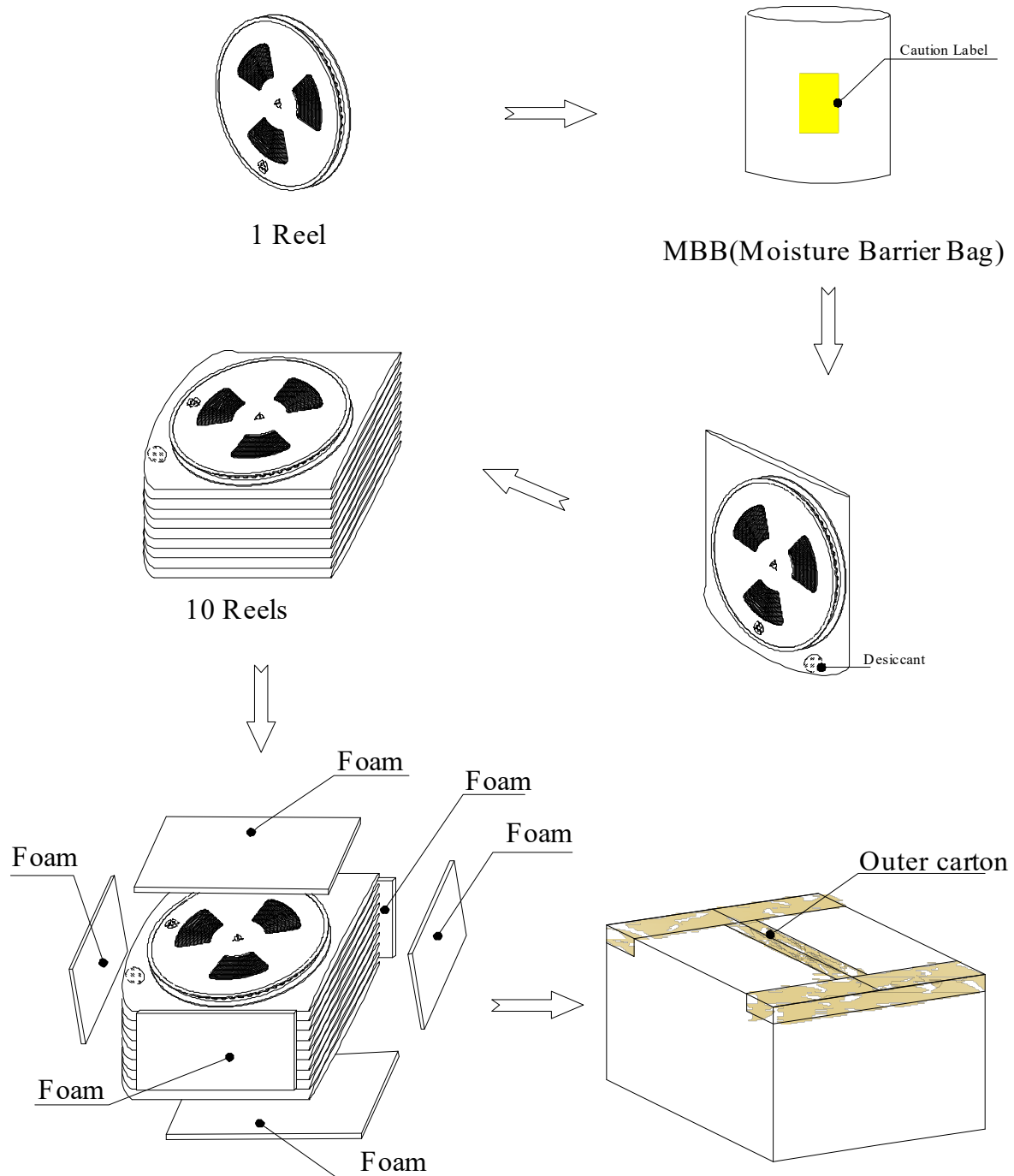


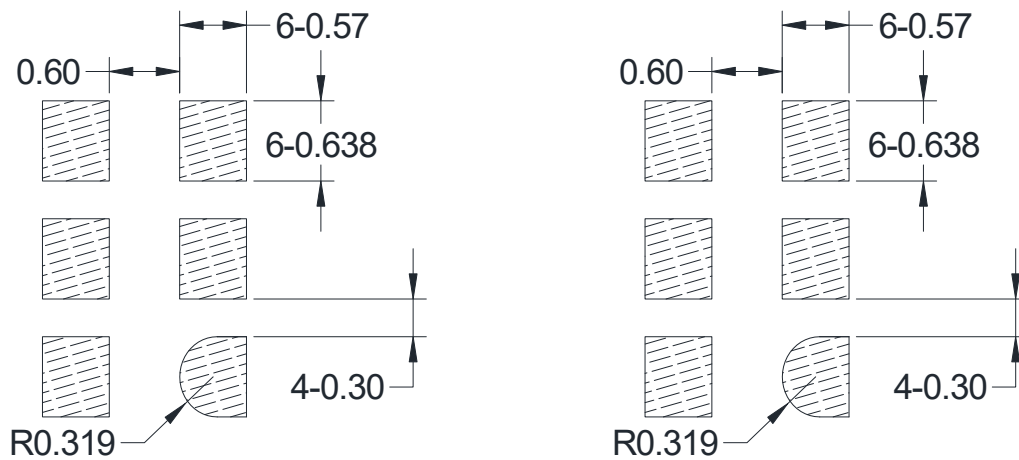
Fig. 13 Packaging



Tape and Reel	φ330mm	10,000PCS×1=10,000PCS
Shipping Box	390mm*390mm*235mm	10,000PCS×10=100,000PCS

Application Design Suggestions

Recommended PCB and Stencil Design Pattern



Example Land Pattern Example Solder Stencil Pattern

Notes:

- Dimensions are in millimeters unless otherwise specified.
- Tolerance is $\pm 0.1\text{mm}$ unless otherwise specified.

Temperature Profile during Reflow Process

Table 8 Temperature Profile during Reflow Process

Parameter		Reference	Specification
Average Ramp Rate		T_L to T_P	3°C/sec max
Preheat	Minimum Temperature	T_{SMIN}	150°C
	Maximum Temperature	T_{SMAX}	200°C
	Time T_{SMIN} to T_{SMAX}	t_s	60 sec to 180 sec
Ramp-Up Rate		T_{SMAX} to T_L	1.25°C/sec
Time Maintained Above Liquidous		t_L	60 sec to 150 sec
Liquidous Temperature		T_L	217°C
Peak Temperature		T_P	260°C
Time Within +5°C of Actual Peak Temperature		t_P	20 sec to 40 sec
Ramp-Down Rate		T_P to T_{SMAX}	6°C/sec max
Time +25°C ($t_{25^\circ\text{C}}$) to Peak Temperature			8 min max

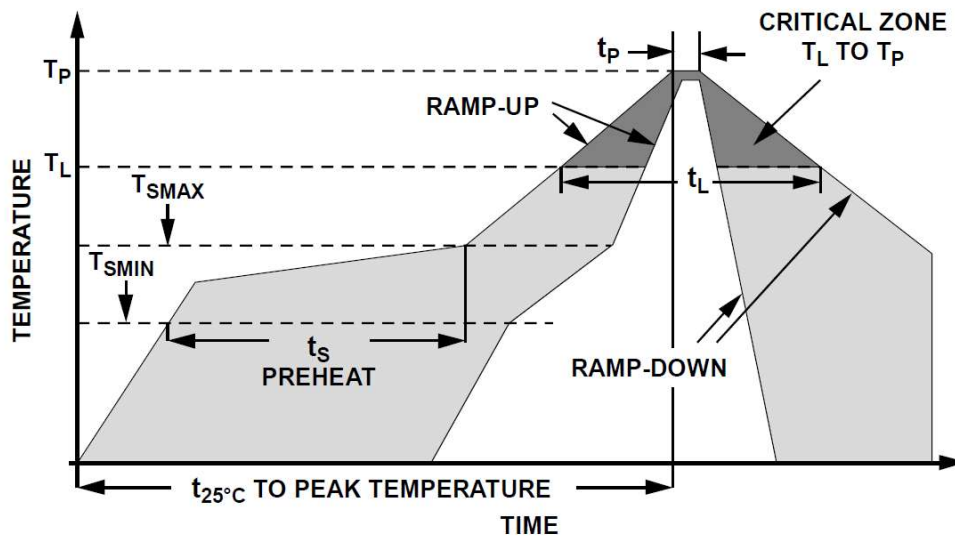


Fig. 14 Reflow Profile

Additional Notes:

- Mic should cool to room temp before next flow cycle if more reflow is needed.
- No more than 3 times reflow is recommended.
- Do not board wash by liquid or ultrasonic after the reflow process.
- Do not pull a vacuum over port hole of the microphone.
- Do not insert any object in port hole of device at any time.
- Suggest SMT the microphone at last time if double side PCBA used.
- Do not seal sound port during reflow .
- If there is any leakage risk, the peak temperature should be set to less than 240°C or more than 255°C.

Recommended Nozzle for Reflow MIC

External diameter is $\Phi 1.8\text{mm}$

Inside diameter is $\Phi 1.2\text{mm}$

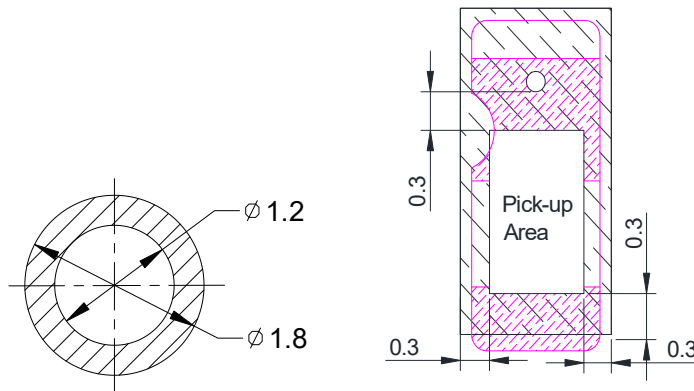


Fig. 15 Recommended nozzle for reflow MIC and Pick-up Area

Special Cautions

Air Rifle Cleaning Restriction

Do not bring air rifle to the port hole directly.

Recommended Condition:

Air pressure < 0.3MPa;

Distance > 5cm;

Time < 5sec.

Package

Do NOT vacuum seal unused material for storage. Vacuum Sealing can cause mic damage.

Storage

The component needs to meet the requirement of MSL (Moisture Sensitivity Level) class 1. Please keep MICs in warehouse with humidity less than 75% and without sudden temperature change, acid air, and any other harmful air or strong magnetic field.

Please protect products against moist, shock, sunburn and pressure.

Please take proper measures against ESD in the process of assembly and transportation.

Please use the shipping package for long-term storage.

Discard

For microphones to be wasted, customer shall follow the regulation of Waste Electrical and Electronic Equipment (WEEE) Directive (2002/96/EC).

Notes: More application suggestions can be found in the latest "MEMS Microphone Application Notes".

Specification Revisions

Date	Version	Description
06-28-2022	V1.0	Preliminary
06-29-2022	V2.0	Updated SNR and frequency response performance
07-19-2022	V3.0	Updated electro-acoustic performance
08-29-2022	V4.0	Updated product name, normal mode PSRR, marking and performance curves
10-24-2022	V5.0	Updated timing specification and packaging details
12-14-2022	V6.0	Updated marking information and clock rise and fall time
05-18-2023	V7.0	Updated reflow specification
12-27-2023	V8.0	Updated power consumption of standby mode
03-28-2024	V9.0	Updated packaging details
04-03-2025	V10.0	Updated packaging details
07-31-2025	V11.0	Updated Gettop information

Gettop 公司销售/技术支持联系方式 (Http://www.gettopacoustic.com)

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